

## 1. General description

High voltage, high speed, planar passivated NPN power switching transistor in a SOT54 (TO92) plastic package intended for use in low power SMPS emitter switching circuits.

## 2. Features and benefits

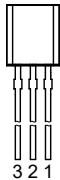
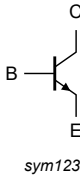
- Fast switching
- High base current drive capability
- High voltage capability
- Very low switching and conduction losses

## 3. Applications

- Emitter-switched low power SMPS circuits
- Self Oscillating Power Supplies
- AC-DC converters
- DC-AC inverters

## 4. Pinning information

Table 1. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	E	emitter	 <p><b>TO-92 (SOT54)</b></p>	 <p>sym123</p>
2	C	collector		
3	B	base		

## 5. Ordering information

Table 2. Ordering information

Type number	Package		
	Name	Description	Version
TB100	TO-92	plastic single-ended leaded (through hole) package; 3 leads	SOT54

## 6. Marking

Table 3. Marking codes

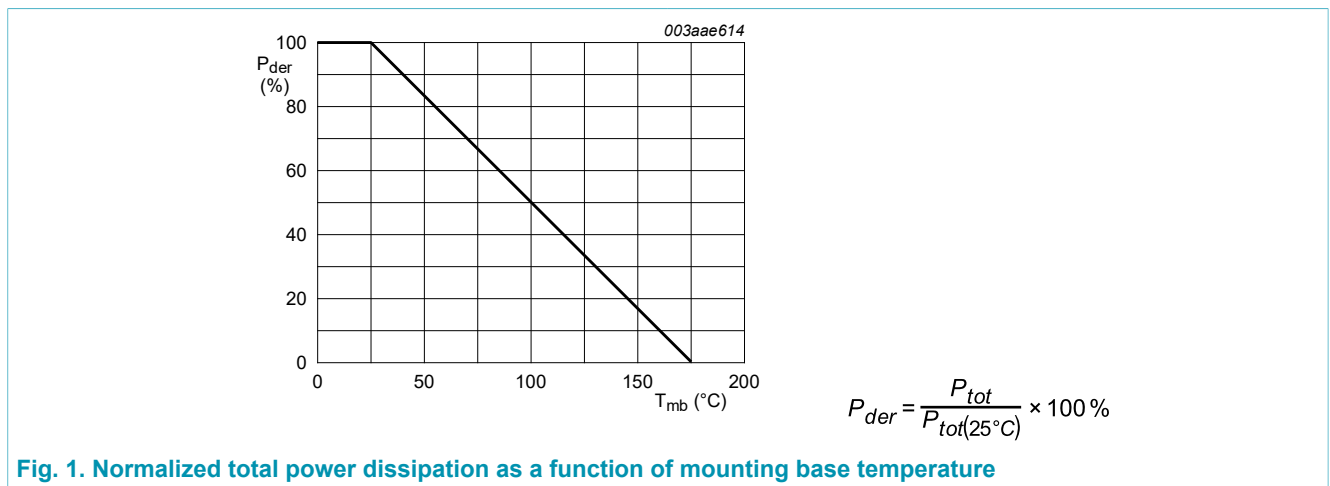
Type number	Marking code
TB100	TB100

## 7. Limiting values

**Table 4. Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>CESM</sub>	collector-emitter peak voltage	V <sub>BE</sub> = 0 V	-	700	V
V <sub>CBO</sub>	collector-base voltage	I <sub>E</sub> = 0 A	-	700	V
I <sub>C</sub>	collector current	DC	-	1	A
I <sub>CM</sub>	peak collector current		-	2	A
I <sub>B</sub>	base current		-	0.5	A
I <sub>BM</sub>	peak base current		-	3	A
P <sub>tot</sub>	total power dissipation	T <sub>lead</sub> ≤ 25 °C; <a href="#">Fig. 1</a>	-	2	W
T <sub>stg</sub>	storage temperature		-65	150	°C
T <sub>j</sub>	junction temperature		-	150	°C



**Fig. 1. Normalized total power dissipation as a function of mounting base temperature**

### 8. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$R_{th(j-lead)}$	thermal resistance from junction to lead		-	-	60	K/W
$R_{th(j-a)}$	thermal resistance from junction to ambient free air	printed circuit board mounted; lead length = 4 mm; <a href="#">Fig. 2</a>	-	150	-	K/W

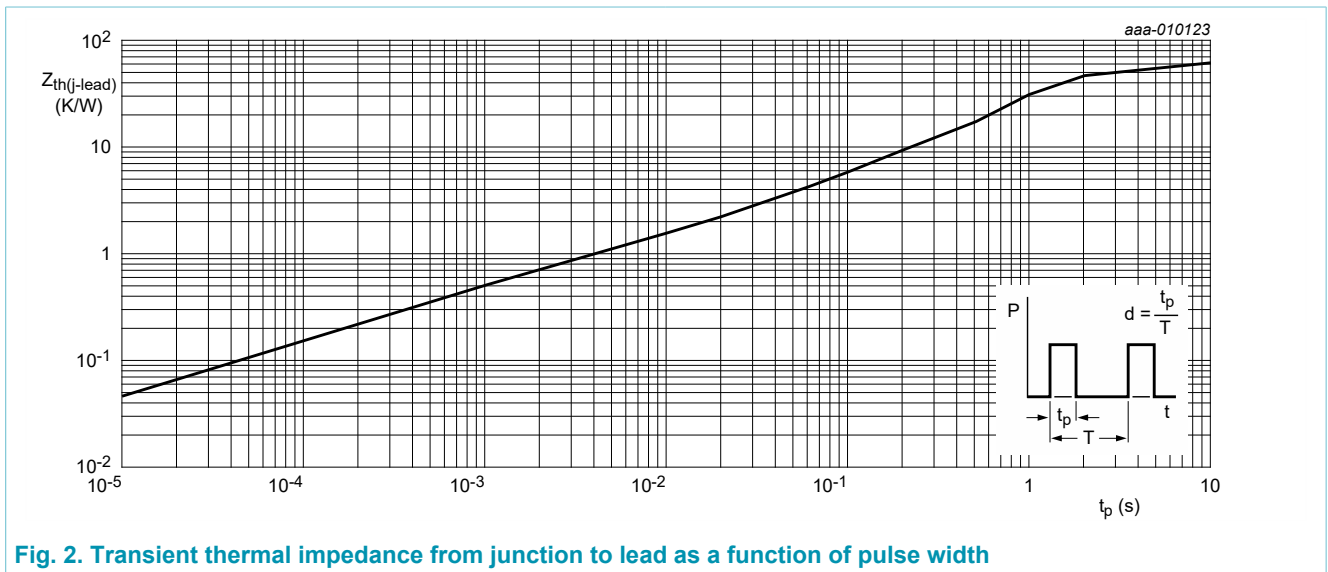


Fig. 2. Transient thermal impedance from junction to lead as a function of pulse width

## 9. Characteristics

Table 6. Characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
<b>Static characteristics</b>						
$I_{CES}$	collector-emitter cut-off current (base shorted)	$V_{BE} = 0\text{ V}; V_{CE} = 700\text{ V}$	-	0.8	100	$\mu\text{A}$
		$V_{BE} = 0\text{ V}; V_{CE} = 700\text{ V}; T_j = 125\text{ }^\circ\text{C}$	-	2	500	$\mu\text{A}$
$I_{EBO}$	emitter-base cut-off current (collector open)	$V_{EB} = 9\text{ V}; I_C = 0\text{ A}; T_{lead} = 25\text{ }^\circ\text{C}$	-	0.05	100	$\mu\text{A}$
$V_{CEsat}$	collector-emitter saturation voltage	$I_C = 0.75\text{ A}; I_B = 0.15\text{ A}; T_{lead} = 25\text{ }^\circ\text{C};$ <a href="#">Fig. 3</a>	-	0.24	1	V
$V_{BEsat}$	base-emitter saturation voltage	$I_C = 0.75\text{ A}; I_B = 0.15\text{ A}; T_{lead} = 25\text{ }^\circ\text{C};$ <a href="#">Fig. 4</a>	-	0.93	1.3	V
$h_{FE}$	DC current gain	$I_C = 10\text{ mA}; V_{CE} = 5\text{ V}; T_{lead} = 25\text{ }^\circ\text{C};$ <a href="#">Fig. 5; Fig. 6</a>	12	22	32	
		$I_C = 100\text{ mA}; V_{CE} = 5\text{ V}; T_{lead} = 25\text{ }^\circ\text{C};$ <a href="#">Fig. 5; Fig. 6</a>	14	24	34	
		$I_C = 0.75\text{ A}; V_{CE} = 5\text{ V}; T_{lead} = 25\text{ }^\circ\text{C};$ <a href="#">Fig. 5; Fig. 6</a>	12	15.5	20	
<b>Dynamic characteristics (resistive load)</b>						
$t_s$	storage time	$I_C = 1\text{ A}; I_{Bon} = 0.2\text{ A}; I_{Boff} = -0.2\text{ A};$ $R_L = 75\ \Omega; V_{BB} = -4\text{ V}; T_{lead} = 25\text{ }^\circ\text{C};$	-	2	-	$\mu\text{s}$
$t_f$	fall time	<a href="#">Fig. 7; Fig. 8</a>	-	320	-	ns

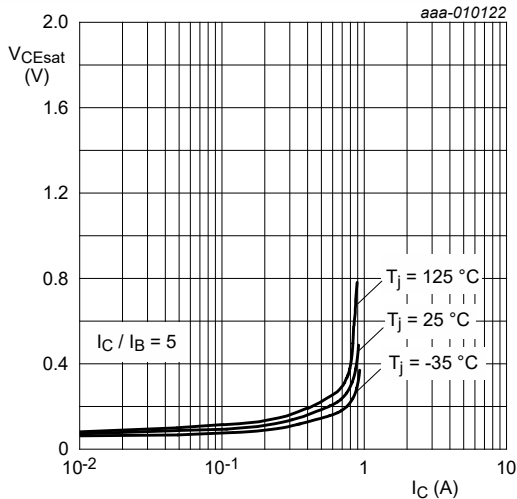


Fig. 3. Collector-emitter saturation voltage as a function of collector current; typical values

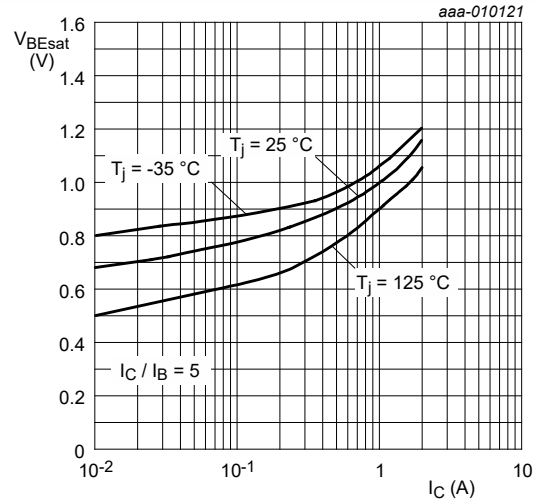


Fig. 4. Base-emitter saturation voltage as a function of collector current; typical values

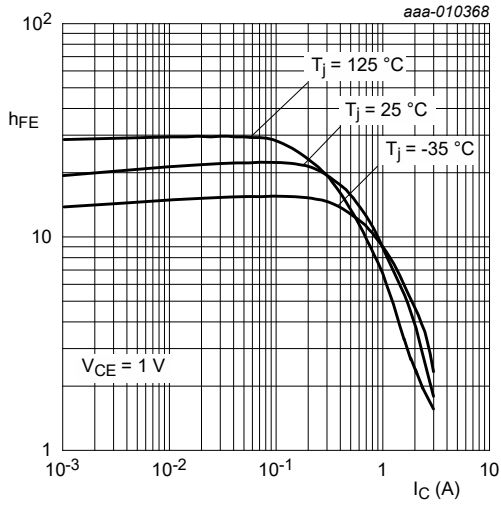


Fig. 5. DC current gain as a function of collector current; typical values

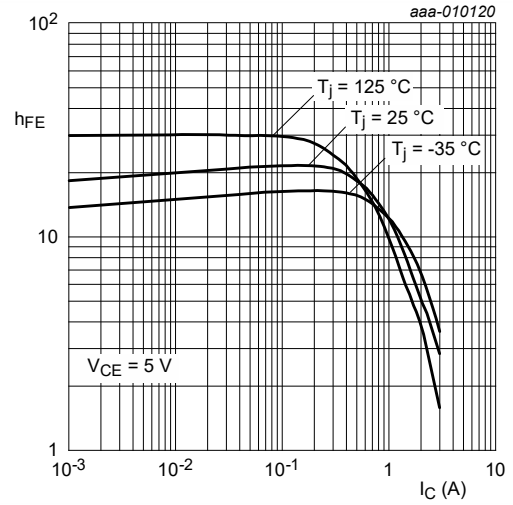


Fig. 6. DC current gain as a function of collector current; typical values

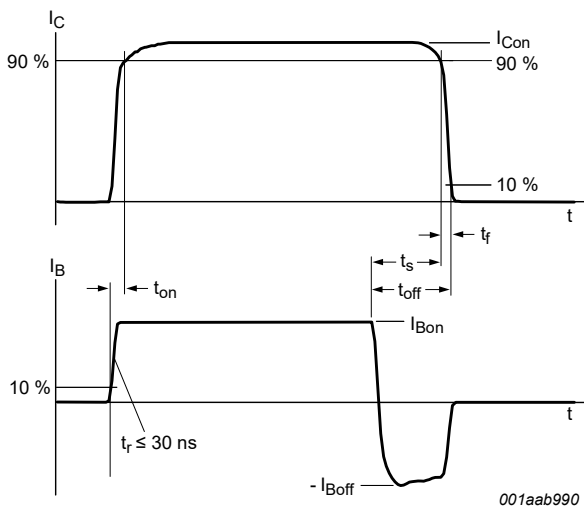
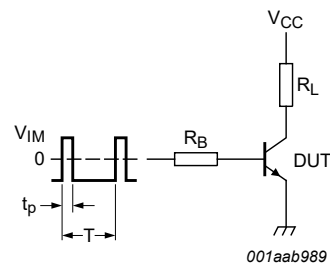


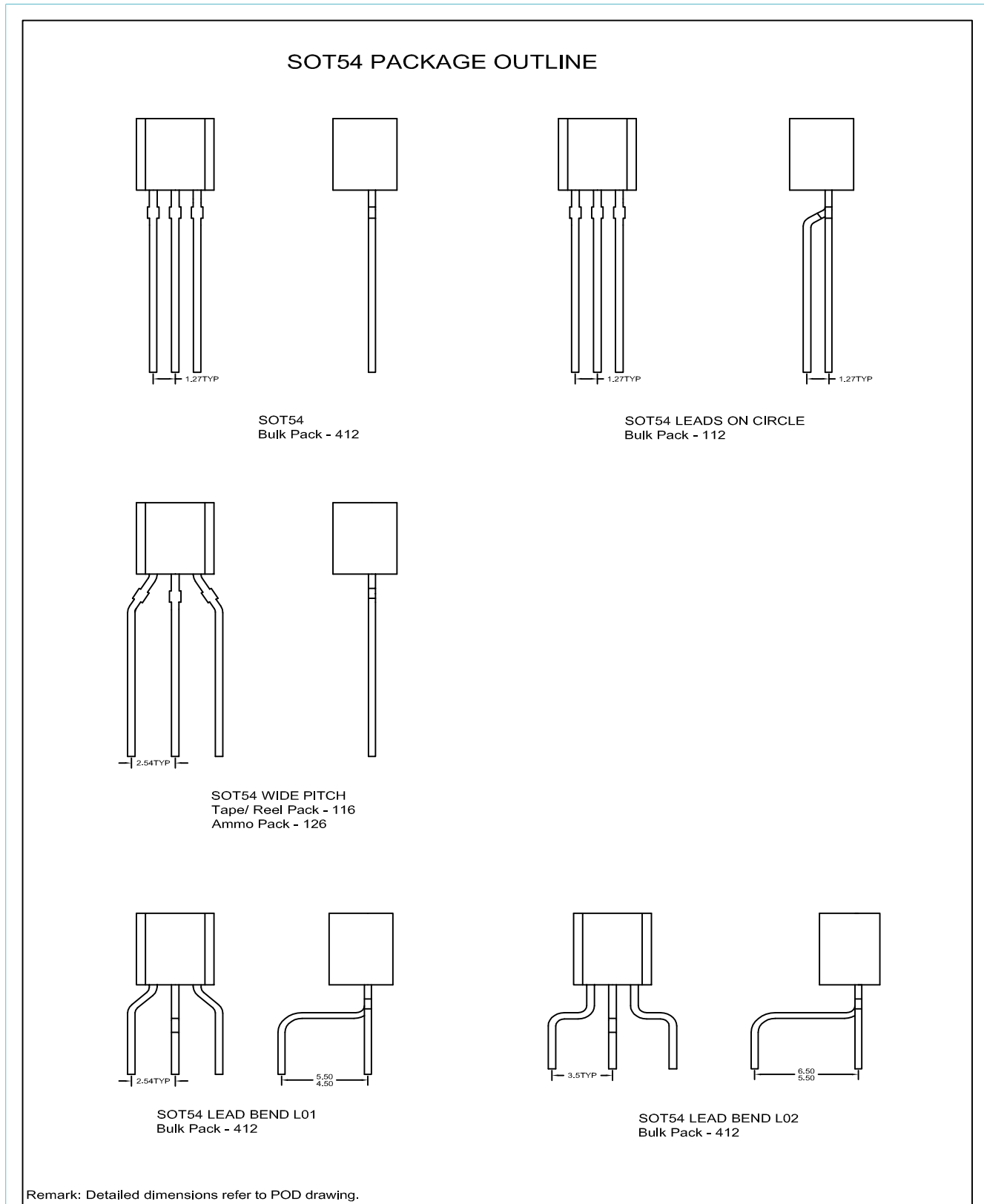
Fig. 7. Switching times waveforms for resistive load



$V_{IM} = -6 \text{ to } +8 \text{ V}; V_{CC} = 250 \text{ V}; t_p = 20 \mu\text{s}; \delta = \frac{t_p}{T} = 0.01$   
 $R_B$  and  $R_L$  calculated from  $I_{Con}$  and  $I_{Bon}$  requirements.

Fig. 8. Test circuit for resistive load switching

### 10. Package outline



**Fig. 9. Package outline TO-92 (SOT54)**

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Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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